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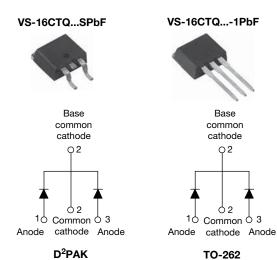
Vishay Semiconductors

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# High Performance Schottky Rectifier, 2 x 8 A



PRODUCT SUMMARY	
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA
I <sub>F(AV)</sub>	2 x 8 A
V <sub>R</sub>	60 V to 100 V
V <sub>F</sub> at I <sub>F</sub>	0.58 V
I <sub>RM</sub>	7 mA at 125 °C
T <sub>J</sub> max.	175 °C
Diode variation	Common cathode
E <sub>AS</sub>	7.5 mJ

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long **FREE** term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS A	OR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	16	A			
V <sub>RRM</sub>		60 to 100	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	А			
V <sub>F</sub>	8 Apk, T <sub>J</sub> = 125 °C (per leg)	0.58	V			
TJ	Range	-55 to 175	٥°			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-16CTQ060SPbF VS-16CTQ060-1PbF	VS-16CTQ080SPbF VS-16CTQ080-1PbF	VS-16CTQ100SPbF VS-16CTQ100-1PbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	60	80	100	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	00	100	V

ABSOLUTE MAXIMUM RATING	S				
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS
Maximum average per leg				8	
forward current per device	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 148 °C, rectangular waveform		16	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	850	
non-repetitive surge current per leg See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	275	A
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 0.50 \ A, \ L = 60$	mH	7.50	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by T <sub>J</sub> maxim	•	0.50	А

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ELECTRICAL SPECIFICATIONS
ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		8 A	T <sub>.1</sub> = 25 °C	0.72	
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=25 C	0.88	v
	VFM (''	8 A	T.I = 125 °C	0.58	V
		16 A	1j = 125 C	0.69	
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B} = Rated V_{\rm B}$	0.55	mA
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	7.0	
Threshold voltage	V <sub>F(TO)</sub>			0.415	V
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		11.07	mΩ
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz), 25 °C	500	pF
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 n	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANI	CAL SPE	CIFICAT	IONS			
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to 175	°C	
Maximum thermal resistance, junction to case per leg		D		3.25		
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	1.63	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	h and greased 0.50		
Approvimeto weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Marking device			Case style D <sup>2</sup> PAK	16CT	16CTQS	
Marking device			Case style TO-262	16CT	ຊ1	



## VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

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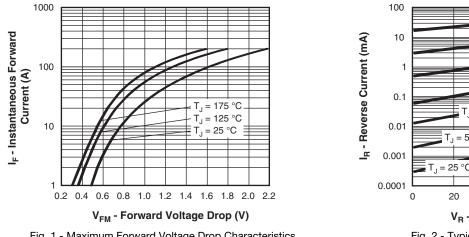
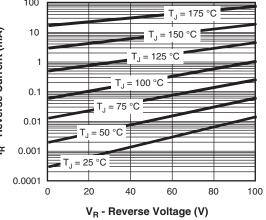
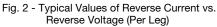


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





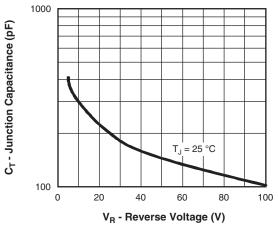


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

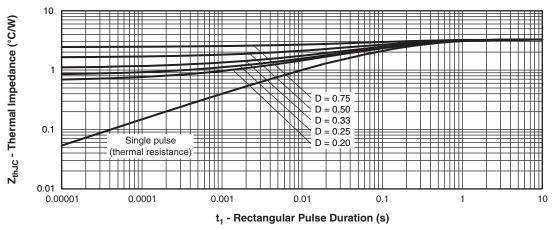
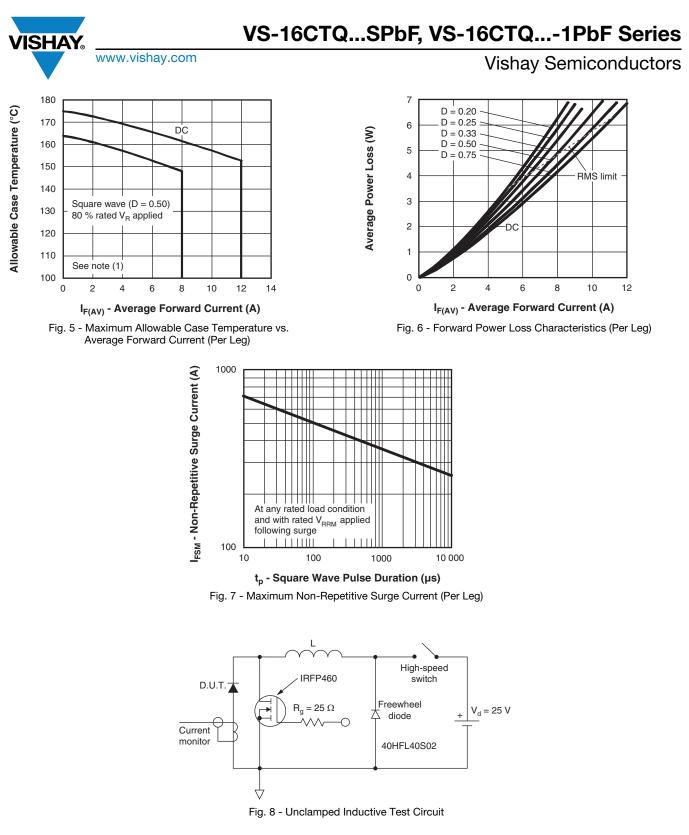


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
  - $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$  applied

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### **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**

VISHA

Device code	VS-	16	С	т	Q	100	S	TRL	PbF
		2	3	4	5	6	7	8	9
	<ol> <li>Vishay Semiconductors product suffix</li> <li>Current rating (16 A)</li> <li>Circuit configuration: C = Common cathode</li> <li>T = TO-220</li> </ol>								
	5 - 6 - 7 -	Volt • S	ottky "C age rati = D <sup>2</sup> PA = TO-2	K	C	)60 = 60 )80 = 80 )00 = 10	V		
l	8 -	• TI • TI	<ul> <li>None = Tube (50 pieces)</li> <li>TRL = Tape and reel (left oriented - for D<sup>2</sup>PAK only)</li> <li>TRR = Tape and reel (right oriented - for D<sup>2</sup>PAK only)</li> <li>PbF = Lead (Pb)-free</li> </ul>						

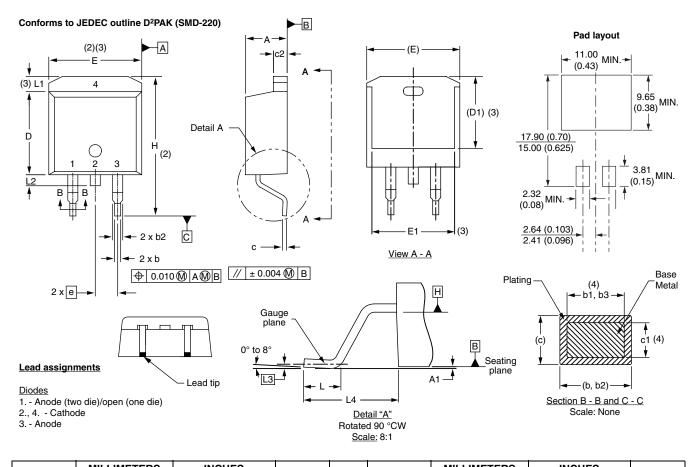
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95014		
Part marking information	www.vishay.com/doc?95008		
Packaging information	www.vishay.com/doc?95032		
SPICE model	www.vishay.com/doc?95279		

Vishay High Power Products

# D<sup>2</sup>PAK, TO-262

### DIMENSIONS FOR D<sup>2</sup>PAK in millimeters and inches

SHA



SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

<sup>(7)</sup> Outline conforms to JEDEC outline TO-263AB

#### Notes

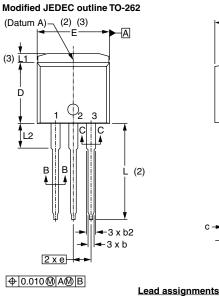
- <sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

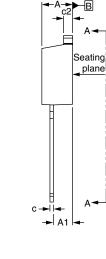
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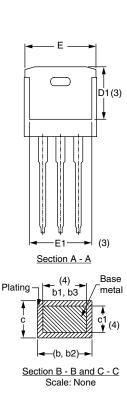
D<sup>2</sup>PAK, TO-262



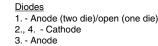
### DIMENSIONS FOR TO-262 in millimeters and inches







Lead tip



	MILLIM	IETERS	INCH	IES	NOTEO
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- <sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

<sup>(6)</sup> Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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